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Nature of charge density wave in kagome metal ScV_6Sn_6 Seongyong Lee^{1,2}, Choongjae Won¹, Jimin Kim^{1,2}, Jonggyu Yoo^{1,2}, Sudong Park^{1,2}, Jonathan Denlinger³, Chris Jozwiak³, Aaron Bostwick³, Eli Rotenberg³, Riccardo Comin⁴, Mingu Kang^{1,4} and Jae-Hoon Park^{1,2}

Recently, kagome lattice materials have emerged as a new model material platform for discovering and engineering novel quantum phases of matter. In this work, we elucidate the driving mechanism of the $\sqrt{3}\times\sqrt{3}$ charge order in a newly discovered kagome metal ScV_6Sn_6 . Through multimodal investigations combining angle-resolved photoemission spectroscopy, phonon dispersion calculations, and phase diagram study, we identify the central role of unstable planar Sn and Sc phonon modes, while the electronic instability and van Hove singularities originating from the V kagome lattice have a marginal influence. Our results highlight that the $\sqrt{3}\times\sqrt{3}$ charge order in ScV_6Sn_6 is fundamentally distinguished from the electronically driven 2×2 charge order in the canonical kagome system AV_3Sb_5 , uncovering a new mechanism to induce symmetry-breaking phase transition in kagome lattice materials.

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INTRODUCTION

Strongly correlated systems and topological materials are two different research areas in condensed matter physics, while exotic electronic phenomena often appear at their intersection¹. Kagome lattice, a two-dimensional network of corner-sharing triangles (Fig. 1a), naturally lies at this intersection thanks to the unique symmetry-protected electronic structure composed of Dirac fermions at K, van Hove singularities (vHS) at M, and a flat band across the whole Brillouin zone (Fig. 1a). On one hand, the diverging density of states at the van Hove singularities and flat band fillings can promote various correlated many-body ground states^{2–6}. On the other hand, the linear band crossing at K and the quadratic band touching degeneracy at Γ can be a singular source of Berry curvature and nontrivial topology^{7–9}. Accordingly, the kagome lattice materials offer a promising opportunity to discover novel electronic phenomena at the confluence of correlation and topology, and have attracted significant research interests during the past few years^{10–17}.

A family of AV_3Sb_5 ($A = \text{K}, \text{Rb}, \text{Cs}$, Fig. 1b) represents an archetype kagome system hosting a rich series of emergent electronic orders, including the 2×2 charge order¹⁷, 1×4 stripe order¹⁸, electronic nematicity¹⁹, superconductivity¹⁷, and pair density waves²⁰. The electronic instabilities associated with the vHSs of the V kagome lattice have been proposed as the origin behind these rich behaviors of AV_3Sb_5 ^{21–23}. Among these, the 2×2 charge order (Fig. 1g) exhibits many unconventional characteristics and has been considered a key to understand the exotic physics of AV_3Sb_5 . For example, the 2×2 charge order in AV_3Sb_5 may accompany an imaginary conjugate component called chiral flux order^{24,25}, which may explain the spontaneous time-reversal symmetry breaking^{26,27} and anomalous Hall conductivity²⁸ observed in AV_3Sb_5 without explicit magnetism. Also, an intricate competition between the 2×2 charge order and superconductivity gives rise to the multiple superconducting domes in the phase diagrams of CsV_3Sb_5 ^{29–31}. In this context, understanding the nature of unconventional charge orders in

kagome lattice materials is of fundamental importance in this emerging research field.

Meanwhile, the 2×2 charge order is not the only form of the charge order proposed in the kagome lattice: early theories predicted more diverse forms of charge order to appear at $1/3$, $2/3$, and vHS fillings, including not only the 2×2 charge bond order (Fig. 1g) but also the 1×1 , 2×1 , and $\sqrt{3}\times\sqrt{3}$ charge density waves (Fig. 1h–j)^{32–35}. The latter phases are distinguished from the 2×2 charge bond order in AV_3Sb_5 by the charge disproportionation at each lattice site, which reflects the manifestation of long-range Coulomb interaction. Intriguingly, such charge disproportionation phases in the frustrated kagome lattice geometry have been predicted to host a fractional charge excitation $e/2$ ³³, analogous to the fractional spin excitations in kagome quantum spin liquids³⁶. In this respect, exploring a new kagome system hosting diverse forms of charge order is highly desired, yet has been missing so far.

To this end, we turn our attention to the newly discovered kagome compound ScV_6Sn_6 hosting the novel $\sqrt{3}\times\sqrt{3}$ charge order below $T_{\text{CO}} \approx 92$ K (Fig. 1j)³⁷. The ScV_6Sn_6 belongs to the large family of HfFe₆Ge₆-type '166' kagome metals (Fig. 1c) with a prospect to tune the charge order by broad chemical substitutions¹⁶. However, the origin and nature of the $\sqrt{3}\times\sqrt{3}$ charge order in ScV_6Sn_6 have remained to be understood. On one side, the $\sqrt{3}\times\sqrt{3}$ charge order may be a consequence of the intrinsic electronic instability of the kagome lattice as predicted from the extended Hubbard model since the early 2010s (Fig. 1j)^{32–34}. The ScV_6Sn_6 shares the partially filled V kagome lattice with the AV_3Sb_5 , so it is tempting to suggest that the same vHS instability of AV_3Sb_5 also contributes to the charge order in ScV_6Sn_6 . On the other side, the X-ray refinement of the charge order structure revealed the dominant displacement of the Sc and Sn atoms, while the displacement within the V kagome lattice is marginal³⁷. Moreover, the $\sqrt{3}\times\sqrt{3}$ charge order is not generally observed in RV_6Sn_6 series ($R = \text{Sc}, \text{Y}$, and rare earth elements), suggesting that extrinsic factors specific to ScV_6Sn_6 may play a role.

In this work, we established the origin of the $\sqrt{3}\times\sqrt{3}$ charge order in ScV_6Sn_6 by comprehensively mapping its electronic

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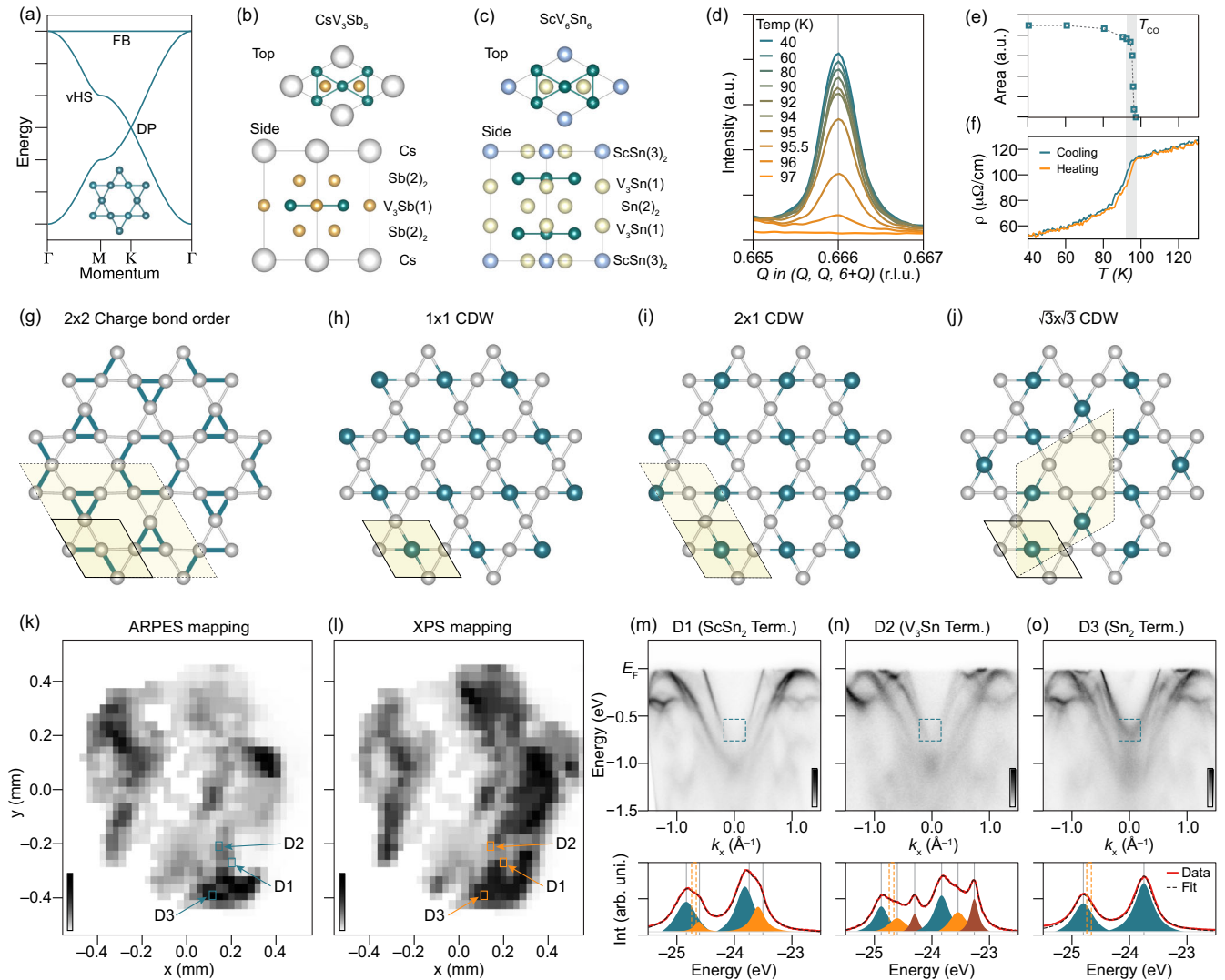


Fig. 1 Novel charge orders in kagome metal. **a** Prototypical electronic structure of the kagome lattice featuring the Dirac point, vHS, and flat band. Inset displays the lattice structure. **b, c** Crystal structure of kagome metals CsV_3Sb_5 (**a**) and ScV_6Sn_6 (**b**) sharing the same V kagome plane. **d, e** Temperature-dependent X-ray diffraction profile and integrated peak area of the (2/3, 2/3, 20/3) charge order peak in ScV_6Sn_6 , respectively. **f** Temperature-dependence of the in-plane resistivity of ScV_6Sn_6 around the charge order transition. **g–j** Various types of charge orders predicted from the extended Hubbard model on kagome lattice. **k, l** Real space mapping of the ARPES and Sn 4*d* XPS intensity of the ScV_6Sn_6 sample. Three different surface domains (D1, D2, and D3) with dramatically different ARPES and XPS spectra were identified. The representative D1, D2, and D3 domain positions are marked in (**k, l**). **m–o**, ARPES (Top panel) and XPS (bottom panel) of ScV_6Sn_6 on D1, D2, and D3 domains, respectively. ARPES spectra was obtained along $\text{K}\Gamma\text{K}$ directions with 120 eV photons. The dashed cyan and orange boxes in (**m–o**) represent the area where the ARPES and XPS intensities are integrated and plotted in (**k, l**). The regions of integrations are chosen to maximize the contrast between different domains in (**k, l**).

structure, phonon dispersion, and phase diagram. Our multimodal approaches coherently point toward that the $\sqrt{3}\times\sqrt{3}$ charge order in ScV_6Sn_6 is tied to the structural components other than the V kagome lattice and is thus fundamentally different from the 2×2 charge order in AV_3Sb_5 originating from the intrinsic electronic instability of V kagome plane.

RESULTS AND DISCUSSION

Basic characterizations of ScV_6Sn_6

We start with the basic characterizations of ScV_6Sn_6 . Our transport measurements revealed a sudden change in electrical resistivity around $T_{\text{CO}} \approx 92$ K, signaling a symmetry-breaking phase transition (Fig. 1f). X-ray diffraction measurements detected commensurate superlattice peaks in the low-temperature phase consistent with the $\sqrt{3}\times\sqrt{3}$ charge ordering (Fig. 1d). Both the abrupt drop in the

diffraction peak intensity at T_{CO} (Fig. 1e) and the small thermal hysteresis in resistivity (Fig. 1f) are indicative of the first-order nature of the transition. Overall, our transport and diffraction characterizations of ScV_6Sn_6 are in close agreement with the original report³⁷.

Before discussing the detailed electronic structure of ScV_6Sn_6 , we briefly remark on the possible surface terminations of the 166 kagome materials. As shown in Fig. 1c, the unit cell of ScV_6Sn_6 consists of one ScSn_2 layer, one hexagonal Sn_2 layer, and two V_3Sn kagome layers; this HfFe_6Ge_6 -type 166 structure can expose complex surface terminations upon cleaving. We note that previous studies on the 166 kagome materials yield inconsistent interpretations on the surface terminations (Supplementary Note 1). To resolve this issue, we performed spatially resolved ARPES and XPS experiments on ScV_6Sn_6 using micro-focused synchrotron radiation (Fig. 1k, l). As summarized

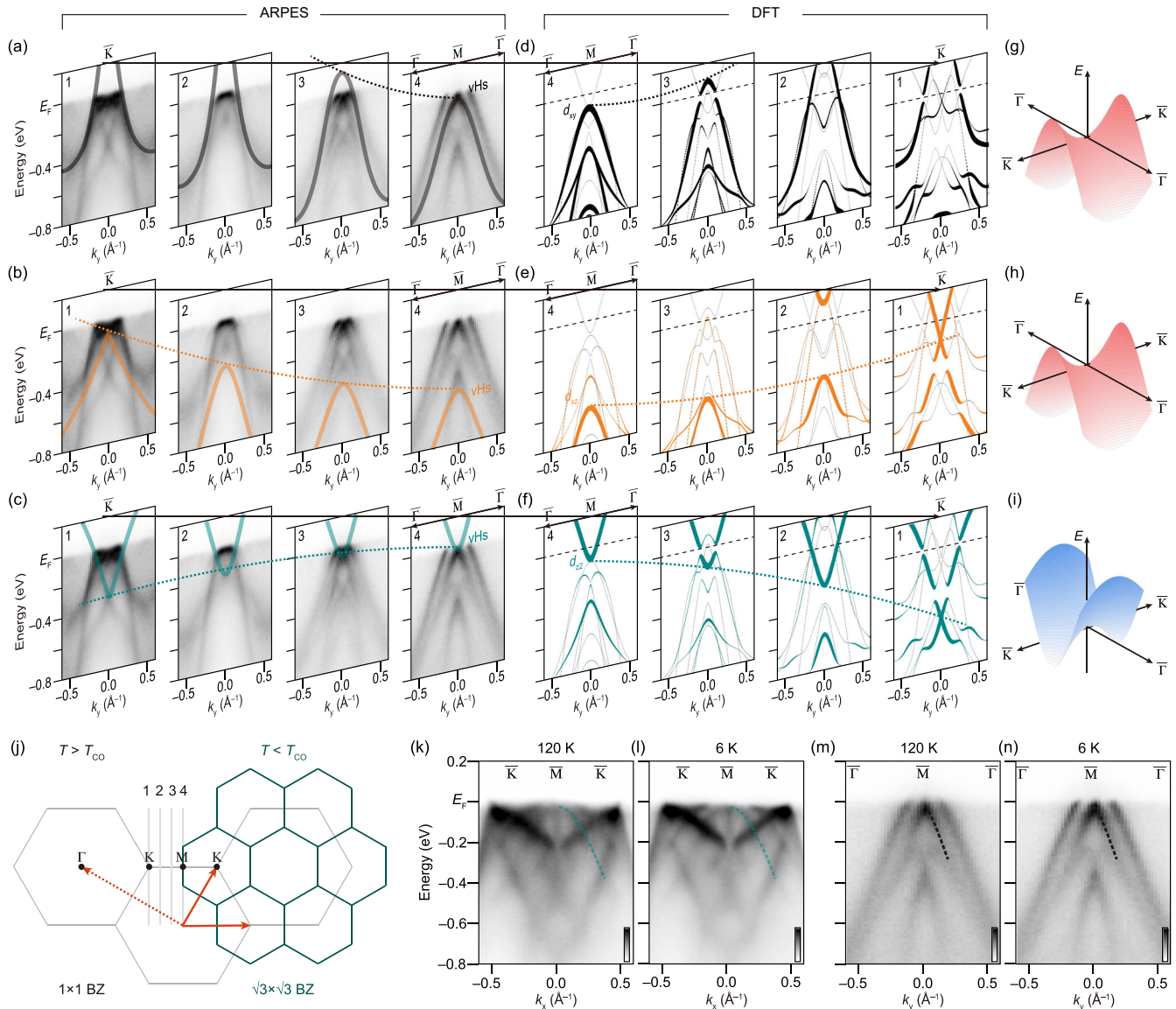


Fig. 2 Characterization of the van Hove singularities in ScV_6Sn_6 . **a, c** Experimentally identified vHS dispersions in ScV_6Sn_6 using ARPES at 6 K. The cut 1–4 plot the ARPES spectra measured perpendicular to the K-M-K direction, with the cut 1 crossing the K point and the cut 4 crossing the M point (see panel j for the exact momentum positions of cut 1–4). We identified three coexisting vHS in ScV_6Sn_6 as marked with black, orange, and cyan guidelines in (a–c), respectively. **d, e** Corresponding DFT band structures of ScV_6Sn_6 for comparison with the ARPES spectra in a–c. The fat bands in d–f represent the spectral weight of the d_{xy} , d_{xz} , and d_{z^2} local orbitals, respectively. **g–i** Schematics of the saddle point dispersions or vHSs. The concavity of vHS is identical for the d_{xy} and d_{xz} vHS, while it becomes opposite for the d_{z^2} vHS. **j** Schematics of the pristine (gray hexagons) and the $\sqrt{3}\times\sqrt{3}$ folded (cyan hexagons) in-plane Brillouin zones of the ScV_6Sn_6 . Dashed and solid orange arrows represent the reciprocal lattice vectors. **k–n** Temperature dependence of the vHSs across the charge order transition. The cyan and black dashed lines are guide for the eye for the d_{z^2} and d_{xy} vHS dispersions near the Fermi level, respectively. All data were collected with 129 eV photons, measuring the $k_z \approx 0$ high-symmetry plane of the three-dimensional Brillouin zone.

in Fig. 1m–o, we clearly identified three different surface domains characterized by dramatically different valence band structures and Sn $4d_{3/2}$, $4d_{5/2}$ core level spectra (D1, D2, and D3 domains, respectively). By comparing the ARPES and XPS spectra at each domain to the slab DFT calculations of various geometries, we unambiguously assigned the D1, D2, and D3 domains to the ScSn_2 , V_3Sn , and Sn_2 surface terminations, respectively (Supplementary Note 2, 3). Below we focus on the results obtained on the V_3Sn termination (D2), which best represents the bulk electronic structure of ScV_6Sn_6 based on the slab calculation (Supplementary Note 3).

van Hove singularities in ScV_6Sn_6

Figure 2 displays our analysis of the low-energy electronic structure of ScV_6Sn_6 . Similar to the case of AV_3Sb_5 , we identified multiple kagome-derived vHSs near the Fermi level. In Fig. 2a–c, we present a three-dimensional stack of the ARPES spectra measured at the vicinity of M point (see the momentum positions of the cut 1–4 in Fig. 2j, see also Supplementary Fig. 4 for the ARPES spectra in the extended momentum range). From these plots, one can comprehensively understand the dispersions along both the Γ -M- Γ (see solid lines in the cut 4) and the K-M-K direction (see dashed lines across the cut 1 to 4). As shown in Fig. 2a, b, we

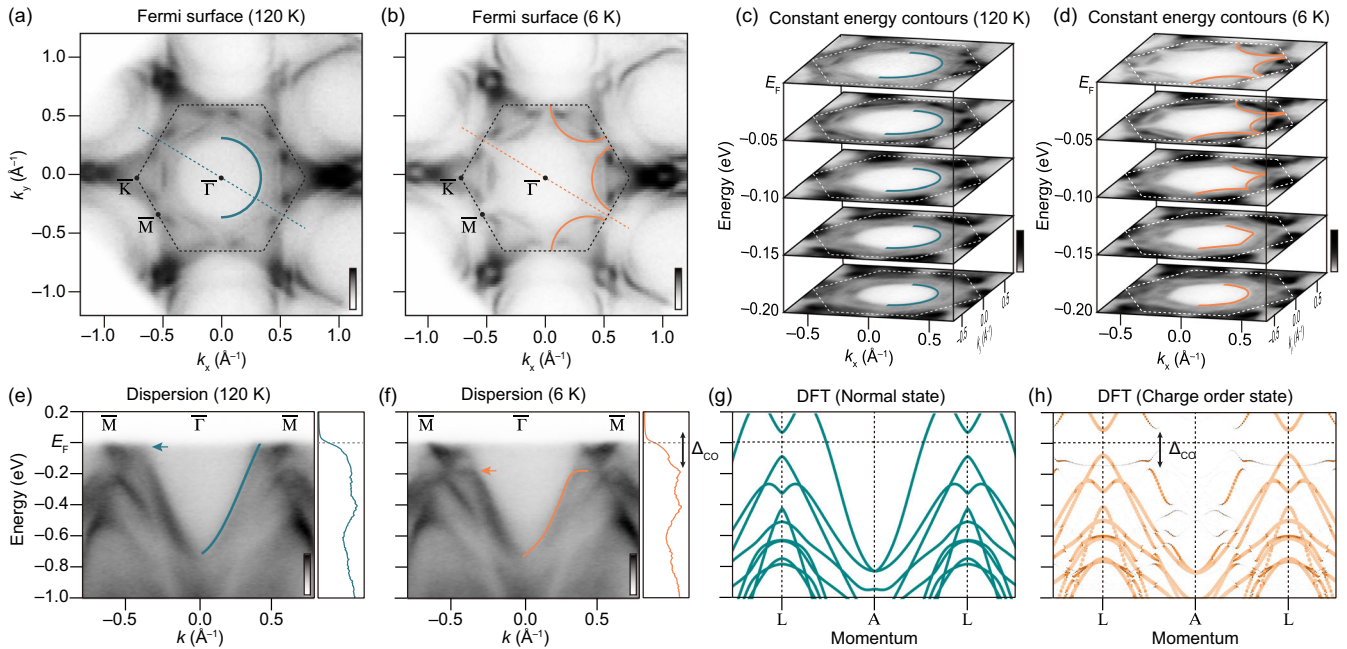


Fig. 3 Fermi surface reconstruction and charge order gap opening across the $\sqrt{3}\times\sqrt{3}$ transition. **a, b** The Fermi surface of ScV_6Sn_6 in the normal and charge-ordered state, respectively. The data were obtained using 115 eV photons corresponding to the $k_z \approx \pi$ high-symmetry plane. The cyan and orange solid lines in a-f are guide for the eye highlighting the band dispersion around the $\bar{\Gamma}$ point. **c, d** Stack of the constant energy contours of ScV_6Sn_6 in the normal and charge-ordered state, respectively. **e, f** Normal and charge-ordered state dispersion of ScV_6Sn_6 measured along the $\bar{\Gamma}$ - \bar{M} high symmetry direction marked in (a, b). The cyan and orange arrows highlight the back bending of the dispersion due to the charge order gap opening at the Fermi level. The right panels in (e, f) display the energy distribution curves measured at the $\sqrt{3}\times\sqrt{3}$ charge order Brillouin zone boundary, i.e., at the two-thirds of $\bar{\Gamma}$ - \bar{M} momentum. The spectral weight shift and charge order gap opening is evident from the energy distribution curves as marked with the black arrow in (f). **g, h** DFT band structure of ScV_6Sn_6 in the normal and charge-ordered state, respectively. The band structure in the charge-ordered state is unfolded to the pristine Brillouin zone to facilitate comparison. The black arrow in (h) indicates the charge order gap observed in the experiment.

identified two bands having electron-like character along the K-M-K direction and hole-like character along the $\bar{\Gamma}$ -M- $\bar{\Gamma}$ direction; these bands thus form saddle point structures or vHSs at the M point as predicted from the model kagome lattice dispersion (see also schematics in Fig. 2g, h). As shown in Fig. 2c, we also observed one additional vHS with inverted concavity, i.e., hole-like dispersion along the K-M-K and electron-like dispersion along the $\bar{\Gamma}$ -M- $\bar{\Gamma}$ direction (see schematics in Fig. 2i). The density functional theory (DFT) calculations in Fig. 2d-f closely reproduce the experimental results, revealing that the three vHSs in Fig. 2a-c respectively originate from the d_{xy} , d_{xz} and d_{zz} local orbital degrees of freedom in the V kagome lattice (Supplementary Note 4). In the kagome lattice, the sublattice character of vHS – pure (*p*) or mixed (*m*) sublattice character – is also a topic of great interest, which critically determines the relevance of the on-site and long-range Coulomb interactions and the leading electronic instabilities^{3,4,23}. By analyzing the sublattice weight distribution near the M point, we revealed that all three vHSs in ScV_6Sn_6 are *p*-type vHSs having pure sublattice character (Supplementary Note 5). In sum, our analysis provides the complete characterizations of the dispersions, orbital characters, and sublattice types of the vHSs in ScV_6Sn_6 .

Notably, the d_{xy} and d_{zz} vHS of ScV_6Sn_6 locate very close to the Fermi level at -0.02 ± 0.01 eV and -0.03 ± 0.02 (Fig. 2a, c), while the d_{xz} vHS is positioned at higher binding energy $\approx -0.40 \pm 0.03$ eV (Fig. 2b). The former vHSs contribute to the diverging density of states at the Fermi level and can in principle promote various electronic instabilities including the charge orderings. This scenario indeed applies to the case of AV_3Sb_5 , where the vHSs at the Fermi level develop charge order gaps and directly contribute to the stabilization of the 2×2 charge order^{21,22,38,39}. To test this scenario in ScV_6Sn_6 , we tracked the temperature evolution of the vHSs across the $\sqrt{3}\times\sqrt{3}$ charge order transition. Comparing the ARPES

dispersions in the normal (Fig. 2k, m) and charge-ordered states (Fig. 2l, n), we observed that all vHSs in ScV_6Sn_6 stay surprisingly unaltered across T_{CO} , despite the fact that the vHS momentum (i.e., M point) lies at the folded Brillouin zone boundary of the $\sqrt{3}\times\sqrt{3}$ charge order (see the schematics in Fig. 2j). This observation indicates that in stark contrast to the case of AV_3Sb_5 , the intrinsic electronic instability of the V kagome lattice plays a marginal role in driving the $\sqrt{3}\times\sqrt{3}$ charge order in ScV_6Sn_6 .

Electronic reconstruction and charge order gap

After ruling out the vHS, we explore the electronic structure of ScV_6Sn_6 in the extended momentum range (Fig. 3), to identify the bands actually relevant to the $\sqrt{3}\times\sqrt{3}$ charge order transition. Figure 3a, b displays the Fermi surfaces of ScV_6Sn_6 measured at the normal and charge-ordered state, respectively. The major reconstruction of the Fermi surface across T_{CO} is apparent from our data: the circular intensity pattern centered at $\bar{\Gamma}$ in the normal state is modified to the star-shaped pattern in the charge-ordered state as highlighted with the cyan and orange guidelines. To better understand this change, we also present the corresponding energy-momentum dispersions along the $\bar{\Gamma}$ - \bar{M} direction in Fig. 3e, f. In the normal state dispersion (Fig. 3e), we observe a large electron pocket centered at $\bar{\Gamma}$, which constructs the circular intensity pattern in the normal state Fermi surface (Fig. 3a). Below T_{CO} (Fig. 3f), this electron band bends toward the higher binding energy and develops a substantial charge order gap at the Fermi level. This opening of the charge order gap depletes the intensity in the Fermi surface along the $\bar{\Gamma}$ - \bar{M} direction and explains the star-shaped Fermi surface observed in the charge-ordered state (Fig. 3b). The momentum position of the charge order gap is at about two-thirds of the $\bar{\Gamma}$ - \bar{M} direction, which excellently matches

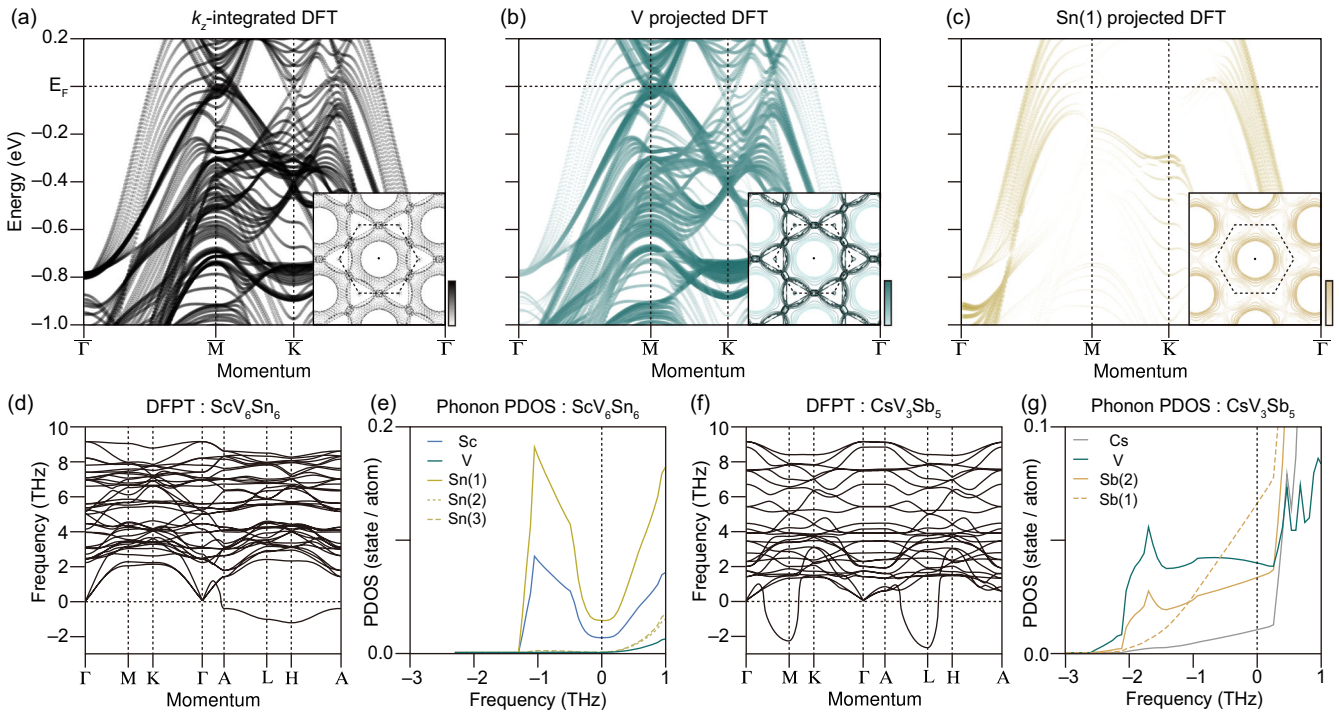


Fig. 4 Element- and site-resolved DFT band structure and DFPT phonon modes of ScV_6Sn_6 . **a–c** k_z -integrated DFT band structure and its projection to the V and Sn(1) orbitals, respectively. The insets display the corresponding Fermi surfaces. **d** The phonon dispersion of ScV_6Sn_6 obtained from the DFPT calculation. **e** The phonon partial density of states of ScV_6Sn_6 projected to the Sc, V, Sn(1), Sn(2), and Sn(3) sites of the unit cell (Fig. 1c). **f, g** The DFPT phonon dispersion and phonon partial density of states of CsV_3Sb_5 , respectively, for comparison with the ScV_6Sn_6 in (d, e).

with the folded Brillouin zone boundary of the $\sqrt{3}\times\sqrt{3}$ phase (Fig. 2j). We note that the band renormalization and charge order gap is also observed in other surface terminations supporting their bulk origin (see Supplementary Fig. 8 for the charge order gaps measured in the D1 termination). As shown in Fig. 3g, h, our DFT calculations closely capture the experimental results, reproducing the large electron pocket at $\bar{\Gamma}$ in the normal state (Fig. 3g) and opening of the charge order gap $\Delta_{\text{CO}} \approx 260$ meV across the Fermi level in the charge order state (Fig. 3h). Notably, the magnitude of the charge order gap in ScV_6Sn_6 is significantly larger than the $\Delta_{\text{CO}} \approx 80$ meV of AV_3Sb_5 despite the comparable T_{CO} in two systems^{21,22}.

Microscopic origin of charge order in ScV_6Sn_6

Importantly, this large electron pocket at $\bar{\Gamma}$, which is closely tied to the $\sqrt{3}\times\sqrt{3}$ charge order, has dominant planar Sn character (i.e., Sn(1) in Fig. 1c). To illustrate this, we present the DFT band structure of ScV_6Sn_6 in Fig. 4a, along with the V and Sn(1) orbital-projected calculations in Fig. 4b, c. The corresponding Fermi surfaces are also shown in the insets. In the V orbital-projected calculation (Fig. 4b), multiple Dirac bands at \bar{K} and van Hove singularities at \bar{M} originating from the V kagome lattice can be clearly identified. Overall, the V spectral weights dominate the Fermi surface near the zone boundary. In contrast, the Fermi surface near the zone center $\bar{\Gamma}$ has dominant Sn(1) orbital character, as shown in the inset of Fig. 4c. We emphasize that it is this Sn(1) band at $\bar{\Gamma}$ that develops the charge order gap and reconstructs the Fermi surface across T_{CO} (Fig. 3), while the V kagome bands near \bar{K} and \bar{M} remain unaltered across T_{CO} (Fig. 2). Our results thus highlight that the $\sqrt{3}\times\sqrt{3}$ charge order of ScV_6Sn_6 is tied to the structural components other than the V kagome lattice, especially to the planar Sn atoms.

The above conclusion from the electronic sector is further supported by our phonon mode calculations presented in

Fig. 4d–g. As shown in Fig. 4d, the phonon dispersions of ScV_6Sn_6 display the continuum of unstable phonon modes centered at H , consistent with the $\sqrt{3}\times\sqrt{3}$ reconstruction in ScV_6Sn_6 at low temperature. By projecting the phonon density of states to the Sc, V, and Sn(1), Sn(2), Sn(3) sites in the unit cell, we revealed that the unstable phonon modes are associated with the structural distortions involving the planar Sn(1) and Sc sites, while the contribution from the V kagome layer is negligible (Fig. 4e). This result not only explains our observation of the large charge order gap on the Sn(1) bands (Fig. 3) and the marginal change of the V kagome bands (Fig. 2), but also is fully consistent with the X-ray refined charge order structure of ScV_6Sn_6 that revealed the dominant distortions in the Sn(1) and Sc sites³⁷. It is also instructive to compare the phonon modes of ScV_6Sn_6 to those of the CsV_3Sb_5 shown in Fig. 4f, g. In stark contrast to the case of ScV_6Sn_6 , the unstable phonon modes of CsV_3Sb_5 at M and L (associated with the 2×2 charge order) accompany the dominant displacement of the V atoms, and reflect the intrinsic electronic instability from the V kagome layers (Supplementary Fig. 11)⁴⁰.

Phase diagram of charge order in $\text{Sc}(\text{V}_{1-x}\text{Cr}_x)_6\text{Sn}_6$

Finally, we construct the phase diagram of $\text{Sc}(\text{V}_{1-x}\text{Cr}_x)_6\text{Sn}_6$ series to understand the evolution of charge order with carrier doping (Fig. 5). The charge order phase remains robust in the wide-doping range, up to doping $x \approx 0.10$ charges per V atom. In the framework of the virtual crystal approximation (Supplementary Fig. 12), this indicates that the charge order phase remains stable up to the order of 120 meV Fermi level shift, further making the electronic scenarios sensitive to the Fermi level, such as the Fermi surface or vHS nesting, unlikely. We note that this response of the charge order to carrier doping is again highly different from CsV_3Sb_5 , where the charge order rapidly vanishes after the $x \approx 0.02 \sim 0.03$ charge doping per V atom, regardless of the doping methods^{31,41}. Such a rapid suppression of charge order in CsV_3Sb_5

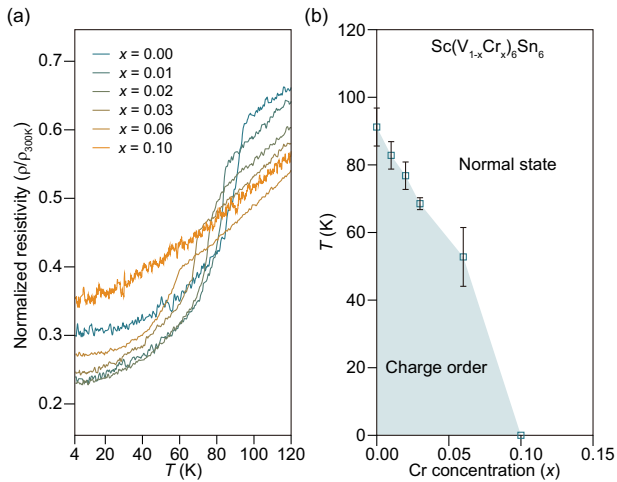


Fig. 5 Phase diagram of charge order in $\text{Sc}(\text{V}_{1-x}\text{Cr}_x)_6\text{Sn}_6$ series. **a** Evolution of the normalized resistivity $T/\rho_{300\text{K}}$ as a function of Cr-doping in $x = 0, 0.01, 0.02, 0.03,$ and 0.06 samples. **b** Doping-temperature phase diagram of the charge order in ScV_6Sn_6 , error bars indicate the range of resistance change during transitions.

with a slight shift of the chemical potential (that disturbs the nesting conditions) is consistent with the electronic origin of the charge order in AV_3Sb_5 . Meanwhile, our powder X-ray diffraction characterizations of the $\text{Sc}(\text{V}_{1-x}\text{Cr}_x)_6\text{Sn}_6$ series revealed that Cr substitution mainly affects the c -axis lattice parameter (Supplementary Fig. 13). Given that the $\sqrt{3}\times\sqrt{3}$ order in ScV_6Sn_6 mainly accompanies the c -axis motion of the Sc and Sn(1) atoms³⁷, we suspect that the reduction of the c -axis lattice parameter is the main driving force of the charge order suppression in the $\text{Sc}(\text{V}_{1-x}\text{Cr}_x)_6\text{Sn}_6$ phase diagram.

In summary, the present work elucidates the origin of the $\sqrt{3}\times\sqrt{3}$ charge order in the newly discovered kagome metal ScV_6Sn_6 . Our comprehensive characterizations of the electronic structure, phonon dispersion, and phase diagram coherently emphasize the essential role of the structural degrees of freedom other than the V kagome lattice in driving the charge order. In this context, the nature of the $\sqrt{3}\times\sqrt{3}$ charge order in ScV_6Sn_6 is fundamentally different from the 2×2 charge order in the archetype kagome metal AV_3Sb_5 , where the electronic instability in the V kagome lattice plays a major role. As discussed in the introduction, the true charge disproportionation phases in the kagome lattice can support the exotica of physics, including the fractionalization of elementary particles. While ScV_6Sn_6 is not an ideal platform to serve this purpose, our study underscores that the search for new kagome quantum materials hosting various types of genuine charge orders should be continued.

Note added in proof: while preparing the manuscript, relevant works on the electronic structure and phonon dispersions of ScV_6Sn_6 were reported^{42–46}. The initial ARPES and optical spectroscopy characterizations in Ref. ^{42–44} failed to identify the charge order gap. Our observation of the charge order gap in the Sn(1) band is consistent with the ARPES spectrum in ref. ⁴⁵. The structural instability identified in our phonon calculation is consistent with the report of ref. ⁴⁶.

METHODS

Single crystal synthesis and characterization

Single crystals of ScV_6Sn_6 and $\text{Sc}(\text{V}_{1-x}\text{Cr}_x)_6\text{Sn}_6$ doping series were grown by typical self-flux methods. Scandium pieces (99.9% Research Chemicals), Vanadium pieces (99.7% Alfa Aesar), and Sn ingot (99.99% Alfa Aesar) were put in the Alumina crucible with

frit disc, then sealed in Ar-gas purged evacuated quartz tube. Ampule was heated at 1100°C for 24 h, then slow cooled to 800°C with $1\sim 2^\circ\text{C}/\text{h}$ cooling ratio. To remove the flux, ampule was centrifuged at 800°C . V and Cr ratios of the doping series were confirmed using energy dispersive spectroscopy. Electrical Resistivity measurements were performed with Physical Properties Measurement System (PPMS, Quantum design) using a conventional 4 probe method. The X-ray diffraction measurements were conducted using $\text{Cu K}\alpha_1$ source ($\lambda = 1.54 \text{ \AA}$) and 6-axis diffractometer. We identified $(1/3\ 1/3\ 19/3)$, $(1/3\ 1/3\ 20/3)$, $(2/3\ 2/3\ 19/3)$, and $(2/3\ 2/3\ 20/3)$ peaks associated with the $\sqrt{3}\times\sqrt{3}\times 3$ charge order, all displaying the same temperature-dependence.

ARPES experiments. ARPES experiments were conducted at Beamline 7.0.2 (MAESTRO) and Beamline 4.0.3 (MERLIN) of the Advanced Light Source, equipped with R4000 and R8000 hemispherical electron analysers (Scienta Omicron), respectively. The samples were cleaved inside ultra-high vacuum chambers with a base pressure better than 4×10^{-11} Torr. To identify high-symmetry planes of the three-dimensional bulk Brillouin zone of ScV_6Sn_6 , the photon energy dependent ARPES measurements were performed in a wide phonon energy range from 60 eV to 200 eV. By comparing the experimental k_z dispersion to the DFT band structure, we identified 129 eV and 115 eV photon energies measuring the $k_z \approx 0$ and $k_z \approx \pi$ high-symmetry planes, respectively. The data in Fig. 2 are acquired with 129 eV photons, while the data in Fig. 3 are measured with 115 eV photons. All normal state (charge-ordered state) data in the main text is obtained at 120 K (6 K) using linear horizontal light polarization, unless specified. We refer to Supplementary Fig. 9 for the data measured in finer temperature steps.

Spatially resolved ARPES and XPS experiments. The real-space mappings of the valence band structure and core level spectra were conducted at Beamline 7.0.2 (MAESTRO) of the Advanced Light Source. To resolve the complex surface domains of ScV_6Sn_6 , we used the micro-focused synchrotron of lateral dimension $30 \times 30 \mu\text{m}^2$. The domain dependent ARPES and XPS spectra are compared to the slab DFT calculations of various geometries, to assign the atomic termination layer to each domain (Supplementary Note 2, 3).

DFT calculations. DFT calculations were performed using the Vienna AB initio Simulation Package software^{47,48}. The generalized-gradient approximation Perdew-Burke-Ernzerhof exchange-correlation functional was chosen to calculate the exchange-correlation energy⁴⁹. The pseudopotential was defined based on the projector augmented-wave method⁵⁰. VASPKit software was used for pre- and post-processing of DFT calculated information⁵¹. For the bulk band calculation of ScV_6Sn_6 , we used the lattice parameters $(a, b, c) = (5.456 \text{ \AA}, 5.456 \text{ \AA}, 9.230 \text{ \AA})$ which is obtained by relaxing the reported single crystal refinement data³⁷. Relaxation is performed at the 350 eV kinetic energy cutoff that fully covers the atomic energy. The static electronic structure was calculated using a Γ -centered k -point mesh, $15 \times 15 \times 8$ for the normal state structure and $8 \times 8 \times 3$ for the charge ordered structure. We present the overall band dispersion of ScV_6Sn_6 in the normal state with and without spin-orbit coupling in Supplementary Fig. 10a. Supplementary Fig. 10b displays the unfolded DFT band dispersion in the charge ordered state. To understand the termination-dependence of the valence band and core level spectra, we performed the slab DFT calculation on all possible charge neutral slab configurations of ScV_6Sn_6 relaxed at the 350 eV kinetic cutoff energy (Supplementary Note 2, 3). Γ -centered $11 \times 11 \times 1$ k -point mesh were used for the slab band calculation. Each slab has 20 atomic layers and the vacuum was fixed at 20 \AA .

DFPT calculations. Phonon dispersions were computed within the density functional perturbation theory (DFPT) framework. Input parameters were generated from the $3 \times 3 \times 2$ supercell using Phonopy software^{52,53}. We compared the phonon modes of two kagome metals, ScV_6Sn_6 and CsV_3Sb_5 . Various smearing factors 0.10, 0.125, 0.15, 0.175, and 0.20 were tested for both compounds. We present the smearing factor-dependent phonon dispersions in Supplementary Fig. 11.

DATA AVAILABILITY

Original data can be found at <https://doi.org/10.7910/DVN/HRCVXB>. Other data supporting the findings of this study are available from the corresponding author on reasonable request.

CODE AVAILABILITY

The datasets presented within this study are available from the corresponding authors upon reasonable request.

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AUTHOR CONTRIBUTIONS

R.C., M.K., and J.-H.P. conceived the project; S.L., J.K., J.Y., and S.P. performed the ARPES experiments and analyzed the resulting data with help from J.D., C.J., A.B., and E.L.; S.L. performed the theoretical calculations; C.W. synthesized and characterized the crystals; S.L. and M.K. wrote the manuscript with input from all coauthors.

COMPETING INTERESTS

The authors declare no competing interests.

ADDITIONAL INFORMATION

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